NSN 5962-01-123-5447

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View Online at https://aerobasegroup.com/nsn/5962-01-123-5447 **Body Length:** 0.440 inches **Body Width:** Between 0.248 inches and 0.325 inches **Body Height:** Between 0.045 inches and 0.085 inches **Maximum Power Dissipation Rating:** 910.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** F-15 radar fscm 76301 **Features Provided:** Hermetically sealed and monolithic and positive outputs and bipolar and w/enable and programmable and w/inhibit **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 40.00 nanoseconds propagation delay time, low to high level output and 84.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:**

82577-932821 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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